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Stocking Distributor

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<u>Vishay Semiconductor/Diodes Division</u> <u>VS-10BQ040HM3/5BT</u>

For any questions, you can email us directly: sales@integrated-circuit.com

Datasheet of VS-10BQ040HM3/5BT - DIODE SCHOTTKY 40V 1A DO214AA Contact us: sales@integrated-circuit.com Website: www.integrated-circuit.com



Diode variation

 E_{AS}

VS-10BQ040HM3

Vishay Semiconductors

High Performance Schottky Rectifier, 1.0 A

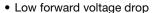


PRODUCT SUMMARY		
Package	SMB	
I _{F(AV)}	1.0 A	
V_{R}	40 V	
V _F at I _F	0.38 V	
I _{RM}	9 mA at 125 °C	
T _J max.	150 °C	

Single die

3.0 mJ

FEATURES





Guard ring for enhanced ruggedness and long term reliability

ROHS COMPLIANT HALOGEN FREE

- Small foot print, surface mountable
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 260 °C
- Meets JESD 201 class 2 whisker test
- AEC-Q101 qualified
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION

The VS-10BQ040HM3 surface mount Schottky rectifier has been designed for applications requiring low forward drop and very small foot prints on PC boards. Typical applications are in disk drives, switching power supplies, converters, freewheeling diodes, battery charging, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS					
SYMBOL	CHARACTERISTICS	VALUES	UNITS		
I _{F(AV)}	Rectangular waveform	1.0	Α		
V _{RRM}		40	V		
I _{FSM}	t _p = 5 µs sine	430	Α		
V _F	1.0 A _{pk} , T _J = 125 °C	0.38	V		
T _J	Range	-55 to +150	°C		

VOLTAGE RATINGS				
PARAMETER	SYMBOL	VS-10BQ040HM3	UNITS	
Maximum DC reverse voltage	V_{R}	40	V	
Maximum working peak reverse voltage	V _{RWM}	40	V	

ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum average forward current	I _{F(AV)}	50 % duty cycle at T _L = 122 °C, rectangular waveform		1.0	Α
Maximum peak one cycle	1	5 μs sine or 3 μs rect. pulse	Following any rated	430	A
non-repetitive surge current	IFSM	10 ms sine or 6 ms rect. pulse	rated V _{RRM} applied	40	A
Non-repetitive avalanche energy	E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 1 \text{A}, L = 6 \text{mH}$		3.0	mJ
Repetitive avalanche current	I _{AR}	Current decaying linearly to zero in 1 μ s Frequency limited by T _J maximum V _A = 1.5 x V _R typical 1.0		Α	

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VS-10BQ040HM3

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ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
		1 A	T 05 °C	0.45	V
Maximum forward voltage drop	V (1)	2 A	T _J = 25 °C	0.52	
See fig. 1	V _{FM} ⁽¹⁾	1 A	T _J = 125 °C	0.38	
		2 A		0.50	
Maximum reverse leakage current	e leakage current	T _J = 25 °C	V _R = Rated V _R	0.1	mΛ
See fig. 2		T _J = 125 °C		9.0	mA
Typical junction capacitance	C _T	$V_R = 5 V_{DC}$, (test signal range 100 kHz to 1 MHz), 25 °C		115	pF
Typical series inductance	L _S	Measured lead to lead 5 mm from package body		2.0	nH
Maximum voltage rate of charge	dV/dt	Rated V _R		10 000	V/µs

 $^{(1)}$ Pulse width = 300 μ s, duty cycle = 2 %

THERMAL - MECHANICAL SPECIFICATIONS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range	T _J ⁽¹⁾ , T _{Stg}		-55 to +150	°C
Maximum thermal resistance, junction to lead	R _{thJL} (2)	DC operation	36	°C/W
Maximum thermal resistance, junction to ambient	R _{thJA}		80	C/VV
Approximate weight			0.10	g
Approximate weight			0.003	oz.
Marking device		Case style SMB (similar DO-214AA)	1	F

Notes

 $[\]frac{dP_{tot}}{dT_J} < \frac{1}{R_{thJA}} \quad \text{thermal runaway condition for a diode on its own heatsink}$

⁽²⁾ Mounted 1" square PCB

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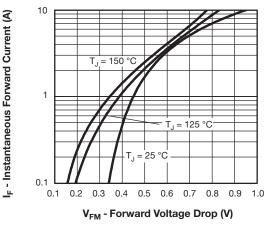


Fig. 1 - Maximum Forward Voltage Drop Characteristics

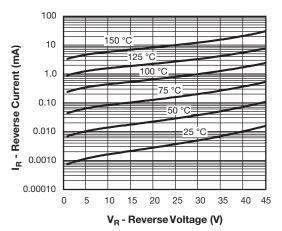


Fig. 2 - Typical Reverse Current vs. Reverse Voltage

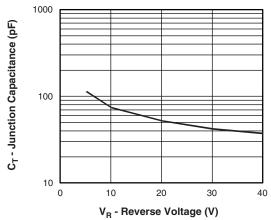


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

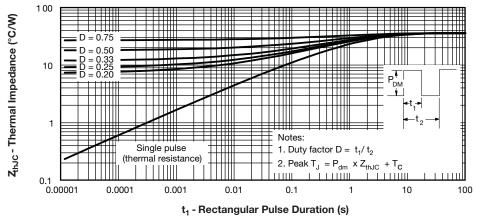


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics (Per Leg)

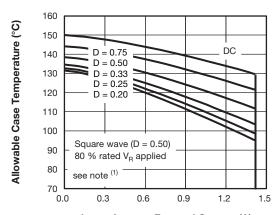
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I_{F(AV)} - Average Forward Current (A)

Fig. 5 - Maximum Average Forward Current vs. Allowable Lead Temperature

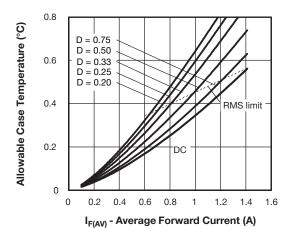


Fig. 6 - Maximum Average Forward Dissipation vs.
Average Forward Current

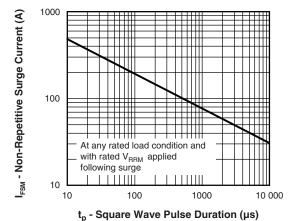


Fig. 7 - Maximum Peak Surge Forward Current vs. Pulse Duration

Note

(1) Formula used: $T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}$; $Pd = Forward power loss = I_{F(AV)} \times V_{FM}$ at $(I_{F(AV)}/D)$ (see fig. 6); $Pd_{REV} = Inverse power loss = V_{R1} \times I_R (1 - D)$; I_R at $V_{R1} = 80 \%$ rated V_R

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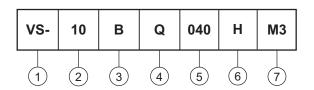


VS-10BQ040HM3

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ORDERING INFORMATION TABLE

Device code



1 - Vishay Semiconductors product

2 - Current rating

3 - B = SMB

4 - Q = Schottky "Q" series

5 - Voltage rating (040 = 40 V)

- H = AEC-Q101 qualified

7 - Environmental digit:

M3 = halogen-free, RoHS compliant and terminations lead (Pb)-free

ORDERING INFORMATION (Example)					
PREFERRED P/N	PREFERRED PACKAGE CODE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION		
VS-10BQ040HM3/5BT	5BT	3200	13" diameter plastic tape and reel		

LINKS TO RELATED DOCUMENTS			
Dimensions <u>www.vishay.com/doc?95401</u>			
Part marking information	www.vishay.com/doc?95403		
Packaging information	www.vishay.com/doc?95404		

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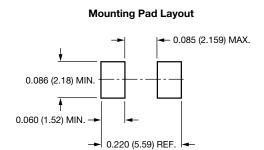
Outline Dimensions

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SMB

DIMENSIONS in inches (millimeters)

0.086 (2.20) 0.077 (1.95) 0.180 (4.57) 0.160 (4.06) 0.096 (2.44) 0.084 (2.13) 0.060 (1.52) 0.060 (1.52) 0.020 (5.59) 0.220 (5.59) 0.205 (5.21)





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